

Features

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 6MHz (Typ.)
- Low Input Bias Current: 1pA (Typ.)
- Low Offset Voltage: 3.5mV (Max.)
- Quiescent Current: 470μA per Amplifier (Typ.)
- Operating Temperature: -40°C ~ +125°C

Small Package:

GS8631 Available in SOT23-5, SOP-8 and SC70-5

Packages

GS8632 Available in SOP-8 and MSOP-8 Packages

GS8634 Available in SOP-14 and TSSOP-14 Packages

General Description

The GS863X have a high gain-bandwidth product of 6MHz, a slew rate of 4.2V/μs, and a quiescent current of 470 μA per amplifier at 5V. The GS863X are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for GS863X. They are specified over the extended industrial temperature range (-40°C to +125°C). The operating range is from 2.1V to 5.5V. The GS8631 single is available in Green SC70-5, SOT23-5 and SOP-8 packages. The GS8632 dual is available in Green SOP-8 and MSOP-8 packages. The GS8634 Quad is available in Green SOP-14 and TSSOP-14 packages.

Applications

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs
- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

Pin Configuration

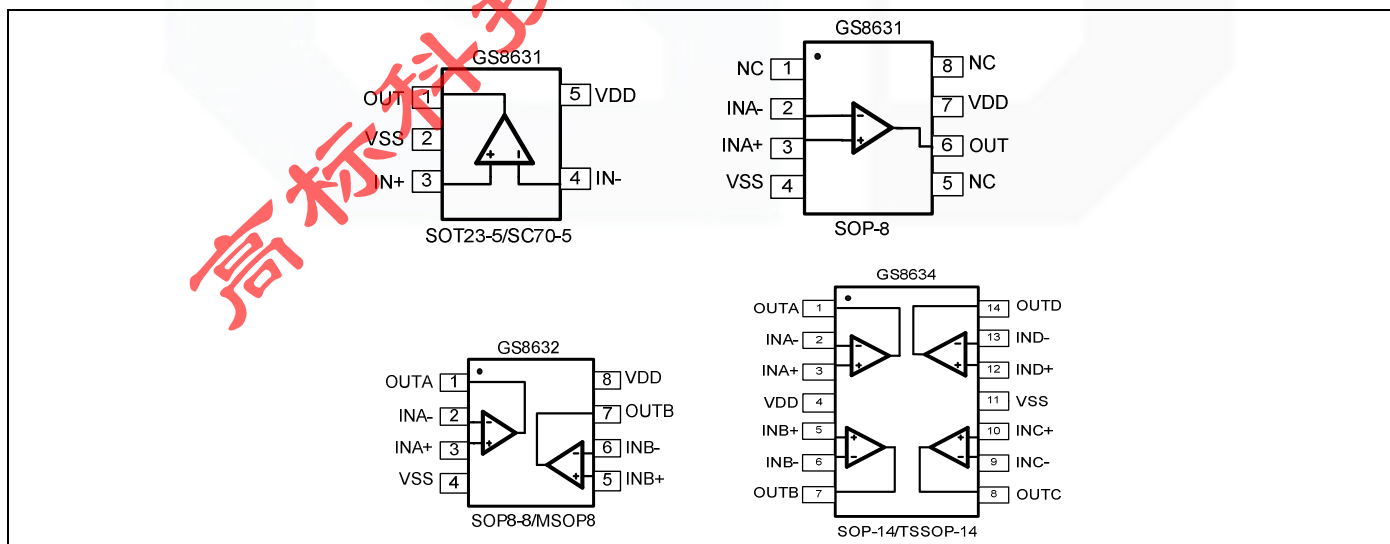


Figure 1. Pin Assignment Diagram

Absolute Maximum Ratings

Condition	Min	Max
Power Supply Voltage (V _{DD} to V _{SS})	-0.5V	+7.5V
Analog Input Voltage (IN+ or IN-)	V _{SS} -0.5V	V _{DD} +0.5V
PDB Input Voltage	V _{SS} -0.5V	+7V
Operating Temperature Range	-40°C	+125°C
Junction Temperature	+160°C	
Storage Temperature Range	-55°C	+150°C
Lead Temperature (soldering, 10sec)	+260°C	
Package Thermal Resistance (TA=+25°C)		
SOP-8, θ _{JA}	125°C/W	
MSOP-8, θ _{JA}	216°C/W	
SOT23-5, θ _{JA}	190°C/W	
SOT23-6, θ _{JA}	190°C/W	
SC70-5, θ _{JA}	333°C/W	
ESD Susceptibility		
HBM	8KV	
MM	400V	

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Package/Ordering Information

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
GS8631	Single	GS8631-CR	SC70-5	Tape and Reel,3000	8631
		GS8631-TR	SOT23-5	Tape and Reel,3000	8631
		GS8631-SR	SOP-8	Tape and Reel,4000	GS8631
GS8632	Dual	GS8632-SR	SOP-8	Tape and Reel,4000	GS8632
		GS8632-MR	MSOP-8	Tape and Reel,3000	GS8632
GS8634	Quad	GS8634-TR	TSSOP-14	Tape and Reel,3000	GS8634
		GS8634-SR	SOP-14	Tape and Reel,2500	GS8634

Partial Circuit Structure

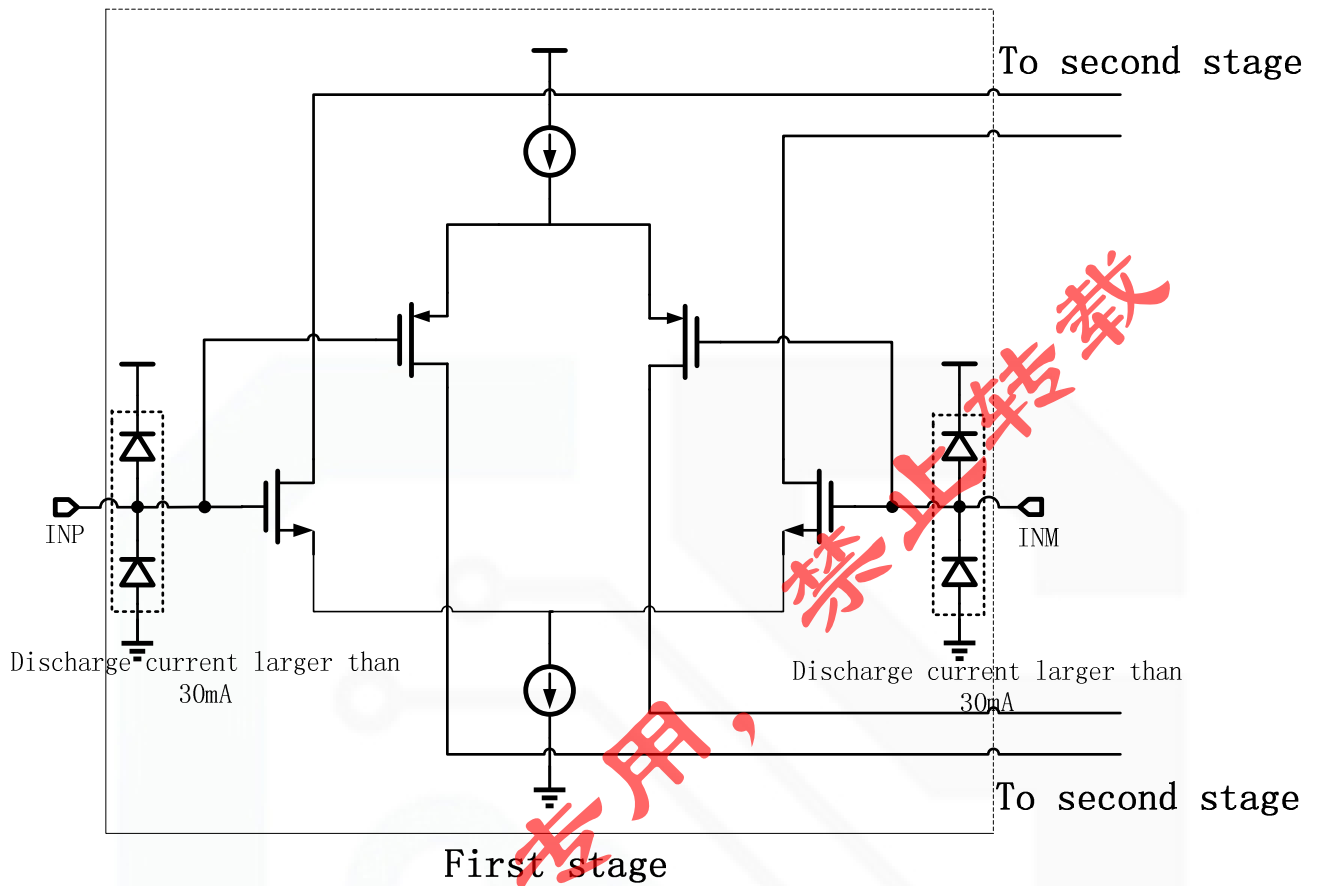


Figure 2. Partial Circuit Structure

Electrical Characteristics

(At $V_S=5V$, $T_A = +25^\circ C$, $V_{CM} = V_S/2$, $R_L = 600\Omega$, unless otherwise noted.)

PARAMETER	CONDITIONS	GS8631/2/4						
		TYP	MIN/MAX OVER TEMPERATURE					
		+25℃	+25℃	0℃ to 70℃	-40℃ to 85℃	-40℃ to 125℃	UNITS	MIN / MAX
INPUT CHARACTERISTICS								
Input Offset Voltage (V _{OS})	V _S = 5.5V	0.8	3.5	3.9	4.3	4.6	mV	MAX
Input Bias Current (I _B)		1					pA	TYP
Input Offset Current (I _{OS})		1					pA	TYP
Input Common Mode Voltage Range (V _{CM})		-0.1 to +5.6					V	TYP
Common Mode Rejection Ratio (CMRR)		V _S = 5.5V, V _{CM} = -0.1V to 4V	90	73	70	70	65	dB
	V _S = 5.5V, V _{CM} = -0.1V to 5.6V	83					dB	MIN
Open-Loop Voltage Gain (A _{OL})	R _L = 600Ω, V _O = 0.15V to 4.85V	97	90	87	86	79	dB	MIN
	R _L = 10kΩ, V _O = 0.05V to 4.95V	108					dB	MIN
Input Offset Voltage Drift (ΔV _{OS} /ΔT)		2.4					μV/℃	TYP
OUTPUT CHARACTERISTICS								
Output Voltage Swing from Rail	R _L = 600Ω	0.1					V	TYP
	R _L = 10kΩ	0.015					V	TYP
Output Current (I _{OUT})		53	49	45	40	35	mA	MIN
Closed-Loop Output Impedance	f = 200kHz, G = 1	3					Ω	TYP
POWER-DOWN DISABLE								
Turn-On Time		4					μs	TYP
Turn-Off Time		1.2					μs	TYP
POWER SUPPLY								
Operating Voltage Range	V _S = +2.5V to +5.5V V _{CM} = (-V _S) + 0.5V		2.1	2.1	2.1	2.1	V	MIN
			5.5	5.5	5.5	5.5	V	MAX
Power Supply Rejection Ratio (PSRR)		91	74	72	72	68	dB	MIN
Quiescent Current/Amplifier (I _Q)		I _{OUT} = 0	470	650	727	750	815	μA

Electrical Characteristics

(At $V_S=5V$, $T_A = +25^\circ C$, $V_{CM} = V_S/2$, $R_L = 600\Omega$, unless otherwise noted.)

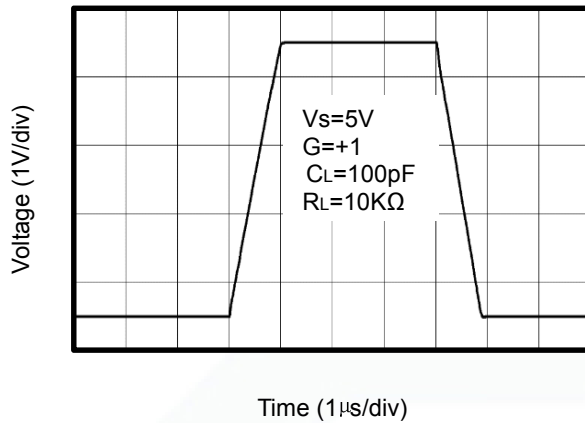
PARAMETER	CONDITIONS	GS8631/2/4							
		TYP	MIN/MAX OVER TEMPERATURE					UNITS	MIN / MAX
		+25℃	+25℃	0℃ to 70℃	-40℃ to 85℃	-40℃ to 125℃			
DYNAMIC PERFORMANCE									
Gain-Bandwidth Product (GBP)	R _L = 10kΩ, C _L = 100pF	6					MHz	TYP	
Phase Margin (φ _O)	R _L = 10kΩ, C _L = 100pF	53					Degrees	TYP	
Full Power Bandwidth (BWP)	< 1% distortion, R _L = 600Ω	250					kHz	TYP	
Slew Rate (SR)	G = +1, 2V Step, R _L = 10kΩ	4.2					V/μs	TYP	
Settling Time to 0.1% (t _s)	G = +1, 2V Step, R _L = 600Ω	0.4					μs	TYP	
Overload Recovery Time	V _{IN} · Gain = V _S , R _L = 600Ω	2.5					μs	TYP	
NOISE PERFORMANCE									
Voltage Noise Density (e _n)							nV / √Hz		
	f = 1kHz	13					nV / √Hz	TYP	
	f = 10kHz	9.5						TYP	

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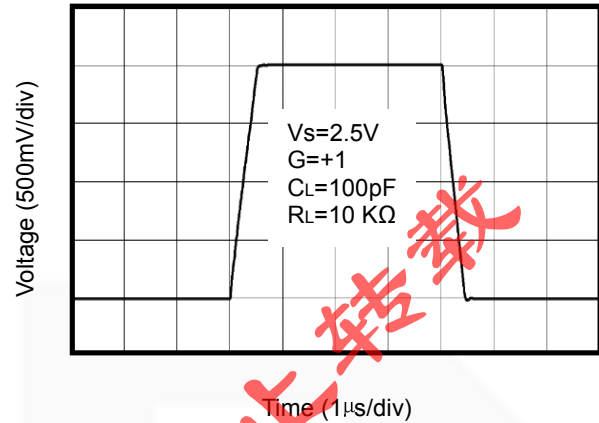
Typical Performance characteristics

(At $V_S=5V$, $T_A = +25^\circ C$, $V_{CM} = V_S/2$, $R_L = 600\Omega$, unless otherwise noted.)

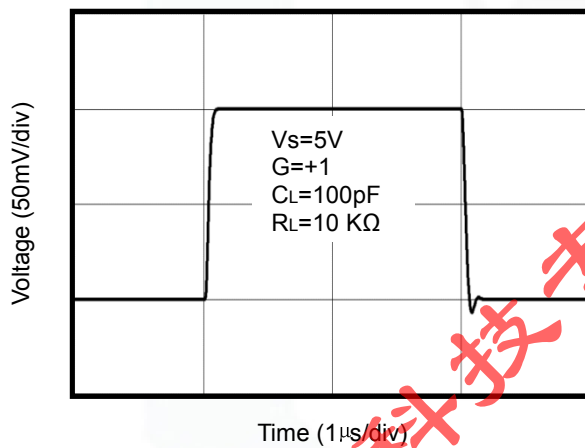
Large-Signal Step Response



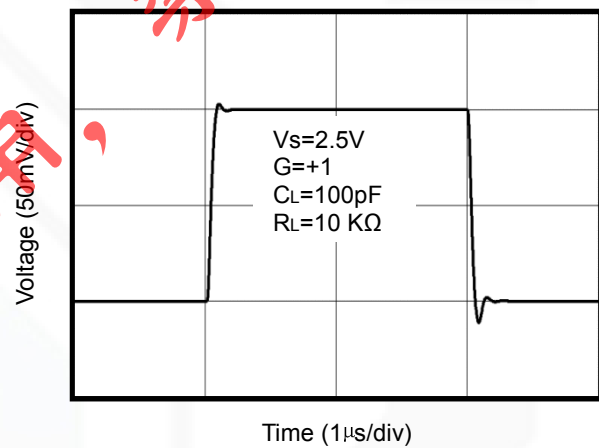
Large-Signal Step Response



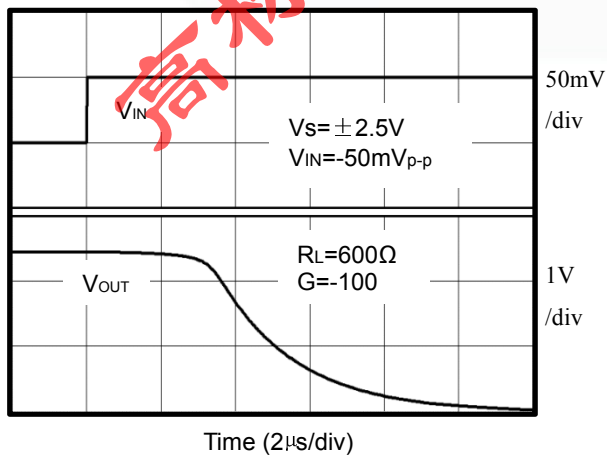
Small-Signal Step Response



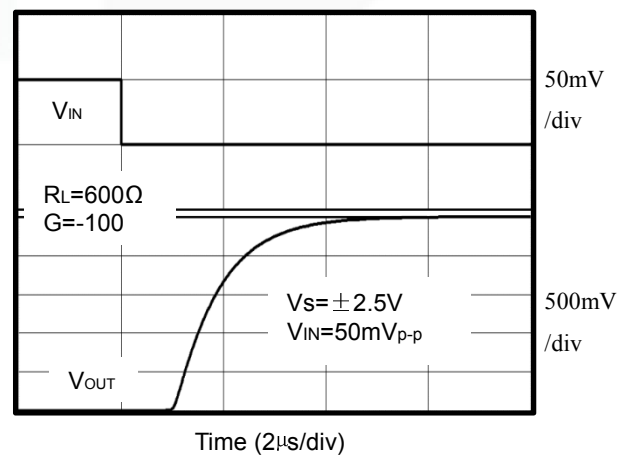
Small-Signal Step Response



Positive Overload Recovery



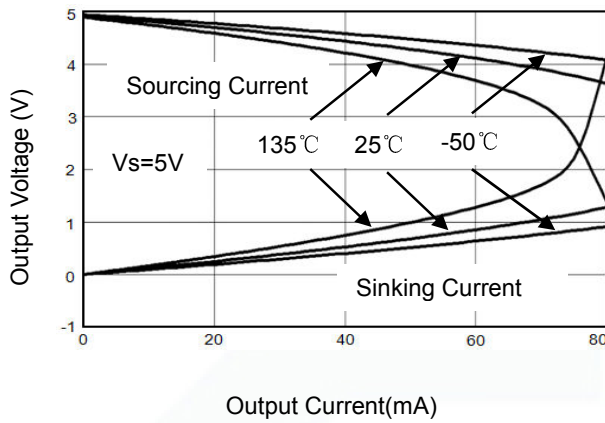
Negative Overload Recovery



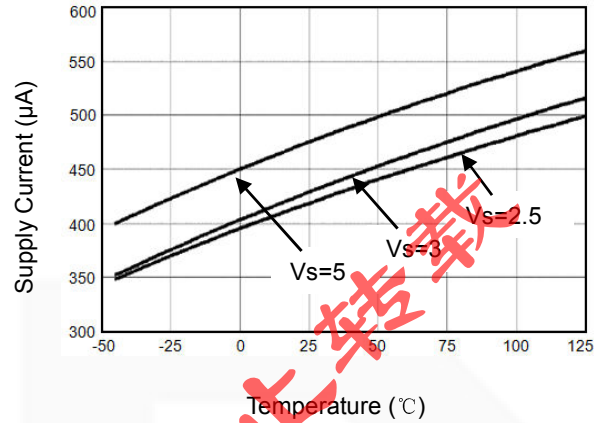
Typical Performance characteristics

(At $V_s=5V$, $T_A = +25^\circ\text{C}$, $V_{CM} = V_s/2$, $R_L = 600\Omega$, unless otherwise noted.)

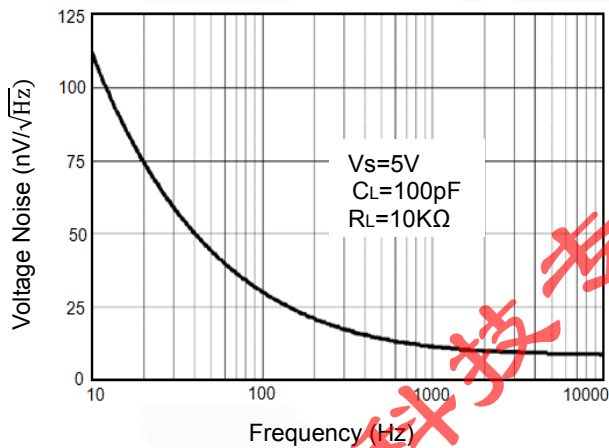
Output Voltage Swing vs. Output Current



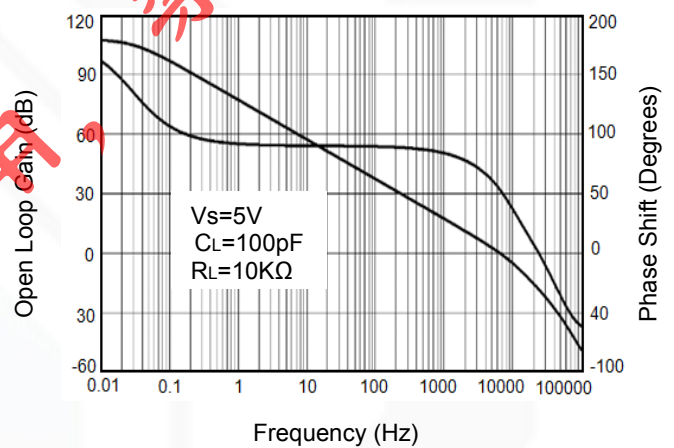
Supply Current vs. Temperature



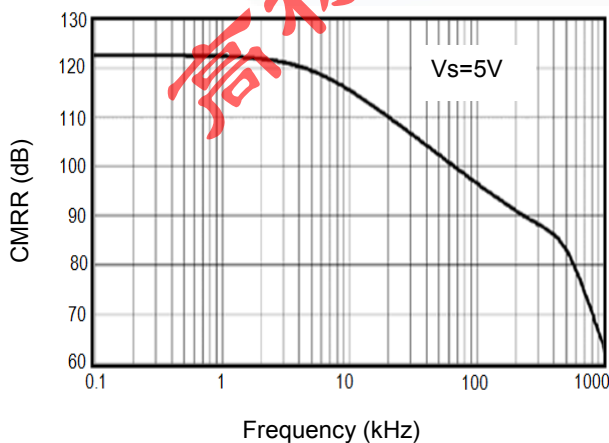
Input Voltage Noise Spectral Density vs. Frequency



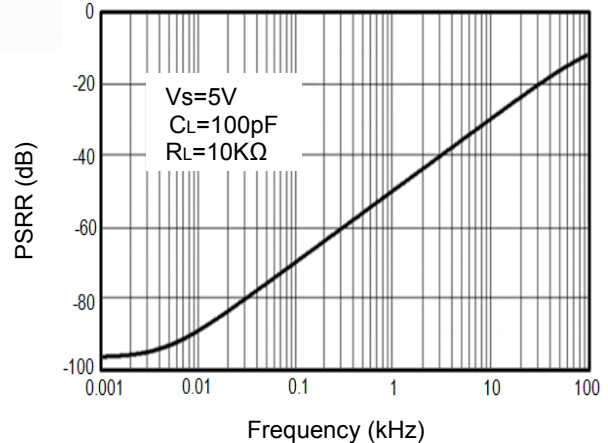
Open Loop Gain, Phase Shift vs. Frequency



CMRR vs. Frequency



PSRR vs. Frequency



Application Note

Size

GS863X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the GS863X series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

GS863X series operates from a single 2.1V to 5.5V supply or dual $\pm 1.05\text{V}$ to $\pm 2.75\text{V}$ supplies. For best performance, a $0.1\mu\text{F}$ ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate $0.1\mu\text{F}$ ceramic capacitors.

Low Supply Current

The low supply current (typical $470\mu\text{A}$ per channel) of GS863X series will help to maximize battery life. They are ideal for battery powered systems

Operating Voltage

GS863X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40°C to $+125^\circ\text{C}$. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

Rail-to-Rail Input

The input common-mode range of GS863X series extends 100mV beyond the supply rails ($V_{SS}-0.1\text{V}$ to $V_{DD}+0.1\text{V}$). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of GS863X series can typically swing to less than 2mV from supply rail in light resistive loads ($>100\text{k}\Omega$), and 60mV of supply rail in moderate resistive loads ($10\text{k}\Omega$).

Capacitive Load Tolerance

The GS863x family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

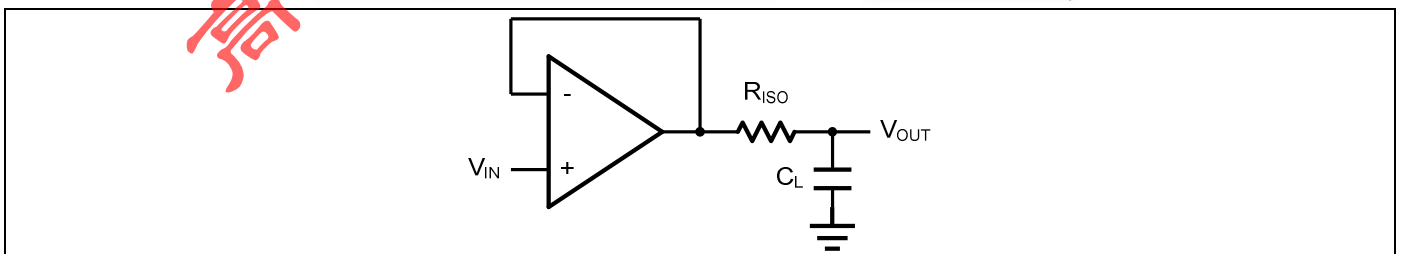


Figure 3. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L . C_F

and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F . This in turn will slow down the pulse response.

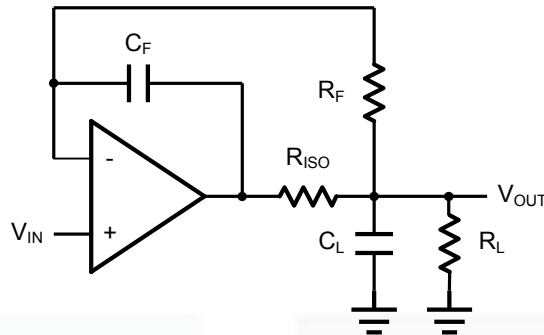


Figure 4. Indirectly Driving a Capacitive Load with DC Accuracy

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Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common to the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using GS863X.

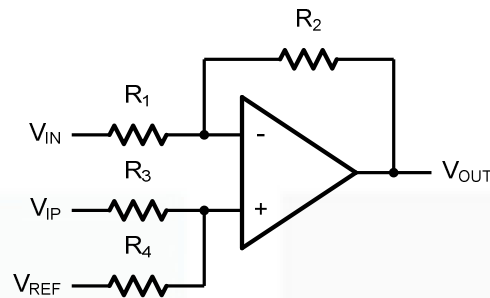


Figure 5. Differential Amplifier

$$V_{OUT} = \left(\frac{R_1 + R_2}{R_3 + R_4} \right) \frac{R_4}{R_1} V_{IN} - \frac{R_2}{R_1} V_{IP} + \left(\frac{R_1 + R_2}{R_3 + R_4} \right) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. $R_1 = R_3$ and $R_2 = R_4$), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_c = 1/(2\pi R_3 C_1)$.

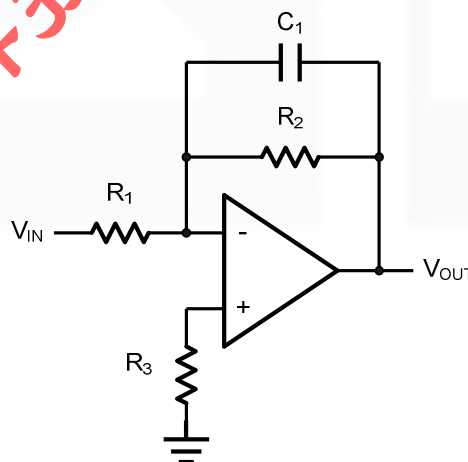


Figure 6. Low Pass Active Filter

Instrumentation Amplifier

The triple GS863X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

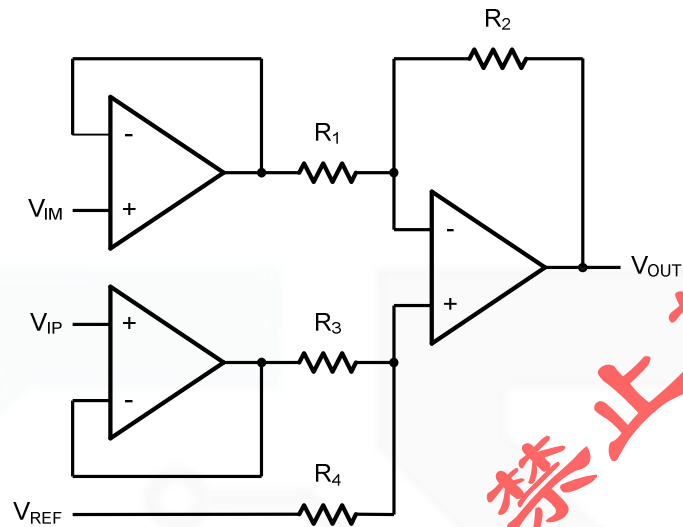
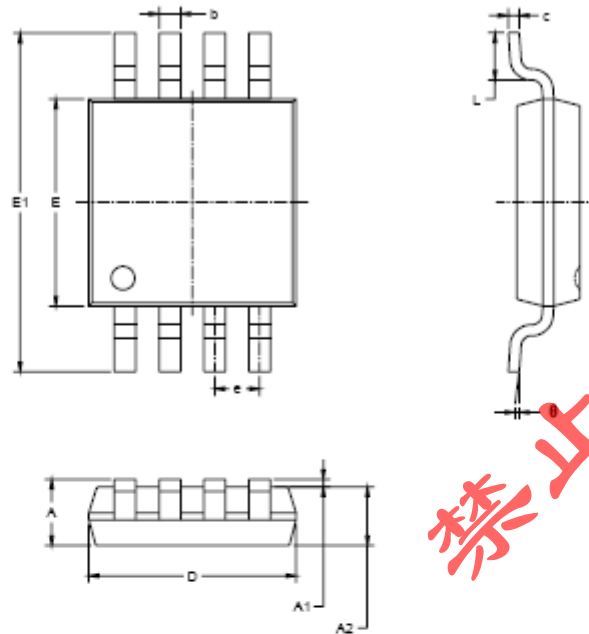


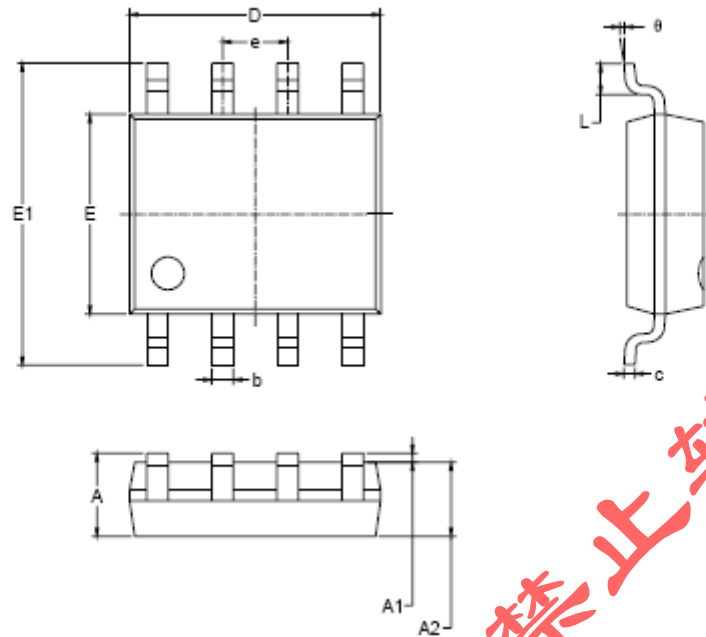
Figure 7. Instrument Amplifier

Package Information

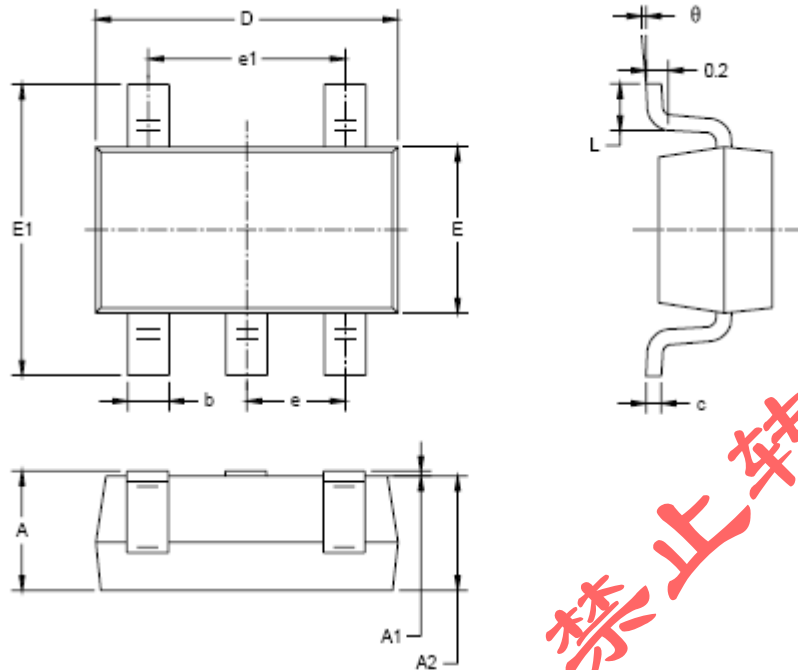
MSOP-8



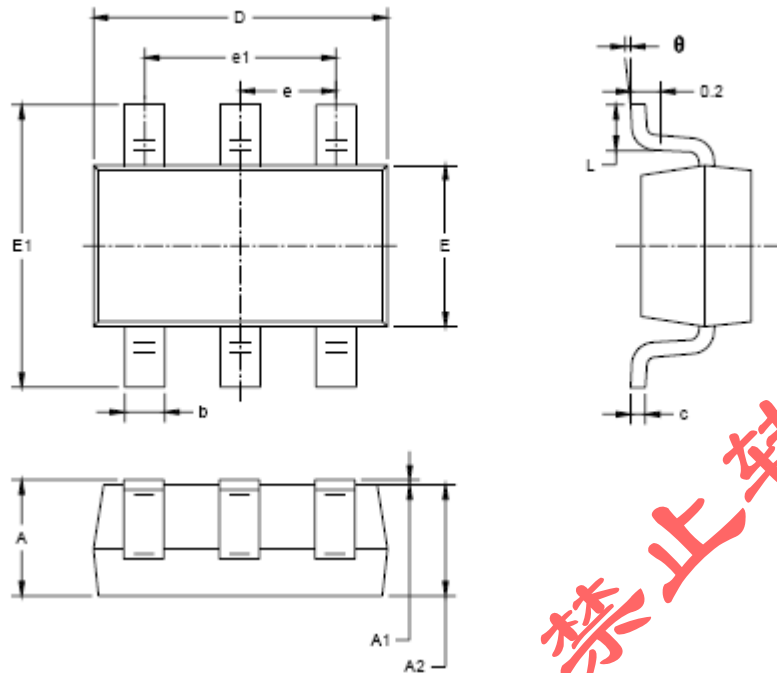
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	8°	0°	8°

SOP-8


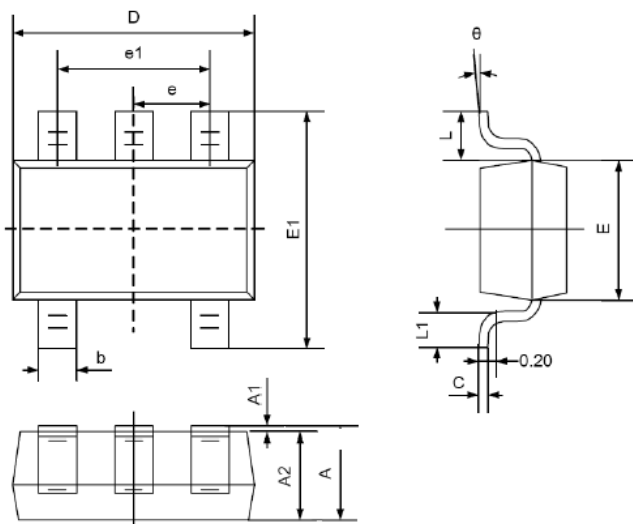
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.530	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

SOT23-5


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.000 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

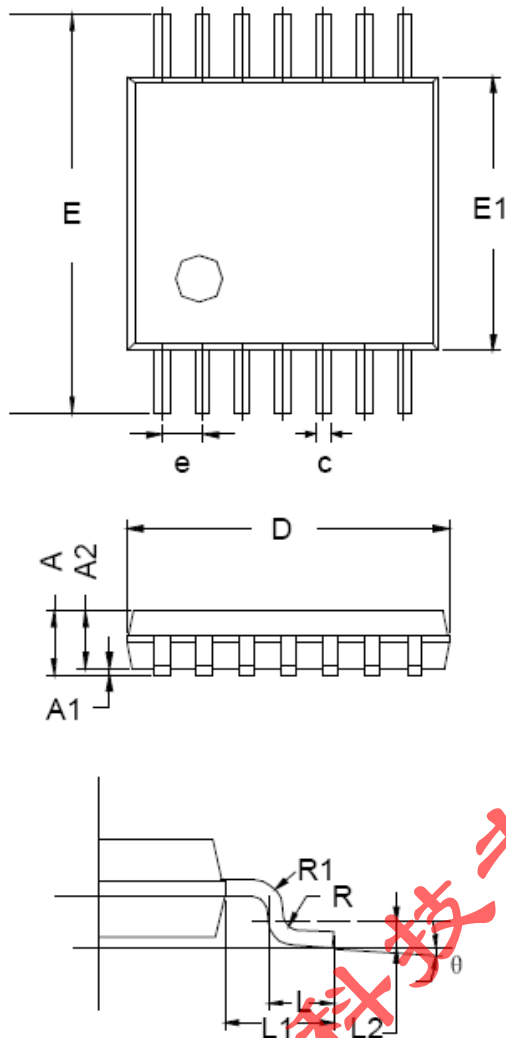
SOT23-6


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SC70-5


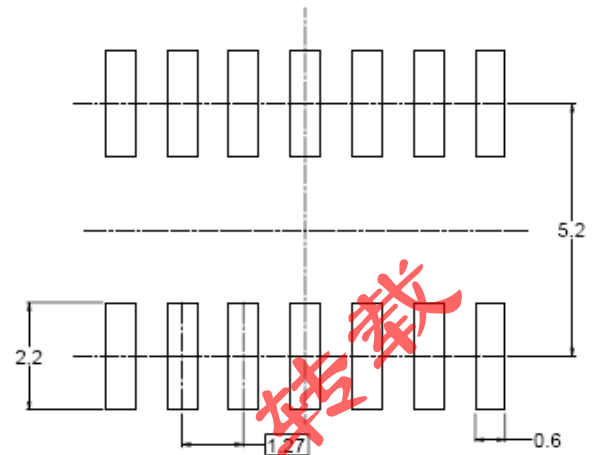
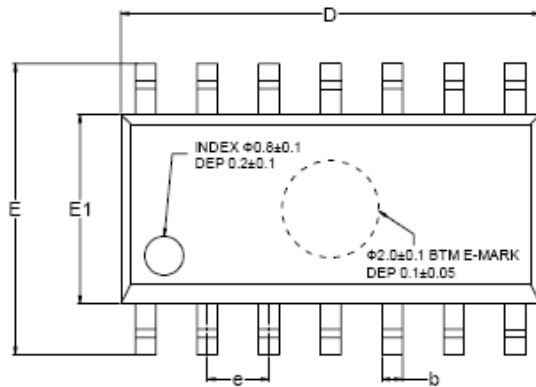
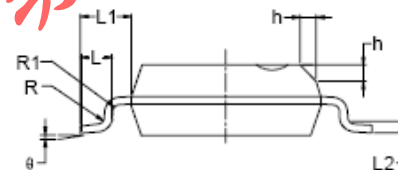
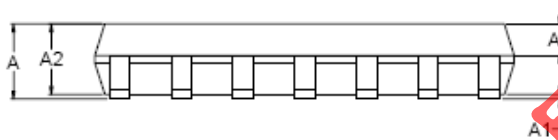
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
C	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

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TSSOP-14


Symbol	Dimensions In Millimeters		
	MIN	TYP	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
b	0.20	-	0.28
c	0.10	-	0.19
D	4.86	4.96	5.06
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
θ	0°	-	8°

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SOP-14

RECOMMENDED LAND PATTERN (Unit: mm)


Symbol	Dimensions In Millimeters			Dimensions In Inches		
	MIN	MOD	MAX	MIN	MOD	MAX
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
e	1.27 BSC			0.050 BSC		
L	0.45		0.80	0.018		0.032
L1	1.04 REF			0.040 REF		
L2	0.25 BSC			0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°